

# SBL10B45IH/DH

### Power Schottky Rectifier - 10Amp 45Volt

### Features

- -Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- -High Junction Temperature Capability
- -Low forward voltage, high current capability
- -High surge capacity
- -Low power loss, high efficiency
- -Halogen-Free

### Application

- -Switching-Mode Power Supply
- -Solar-System Control Box

### ☐ Absolute maximum ratings

Symbol	Ratings	Unit	Conditions	
lF(AV)	10	Α	Average Forward Current	
VRRM	45	V	Repetitive Peak Reverse Voltage	
IFSM	120	Α	Peak Forward Surge Current	
VF	0.50	V	Forward Voltage Drop	
Tj , Tstg	-50 to +150	°C	Operating and Storage Temperature	

### Electrical characteristics

Parameters	Symbol	Ratings	Conditions	
Maximum Instantaneous Forward Voltage	VF	0.55V 0.50V	Per Leg at IF = 5A Tc = 25°C Tc = 125°C	
Maximum Reverse Leakage Current	lr	1.0mA	Per Leg at VR = 45V Tc = 25°C	
Typical Thermal Resistance,Junction to Case	Rθ (j-c)	7 °C/W	Per Leg TO-251 / TO-252	

Note: 1.Mounted on P.C.B with copper pad size 20mm x 30mm, thickness 1.5mm

2.Reverse Surge 3.0A @ 0.004ms, 10 cycle

3.Repetitive Peak Reverse Current (IRRM) 0.5A @ Per Leg at tp = 2µs, 1kHz

December 2018 / Rev.7.2

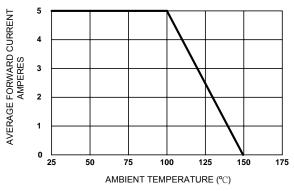
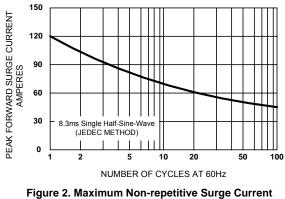


Figure 1. Forward Current Derating Curve



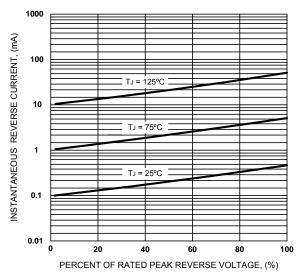


Figure 3. Typical Reverse Characteristics

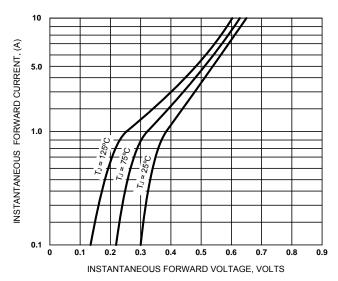


Figure 4. Typical Forward Characteristics

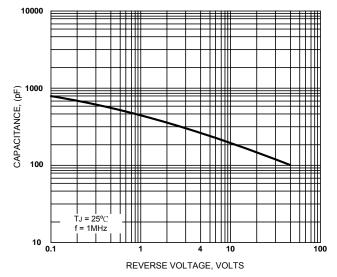
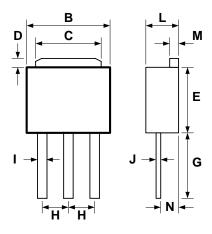
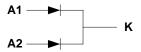


Figure 5. Typical Junction Capacitance

# **SBL10B45IH**

T0-251

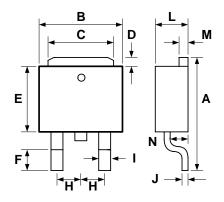


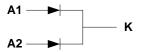


DIMENSIONS					
DIM	INCHES		MILLIMETERS		NOTE
	MIN	MAX	MIN	MAX	NOTE
В	.250	.266	6.35	6.75	
С	.201	.217	5.10	5.50	
D	.033	.053	0.85	1.35	
Е	.228	.248	5.80	6.30	
G	.209	.228	5.30	5.80	
Н	.085	.096	2.15	2.45	
- 1	.030	.041	0.75	1.05	
J	.016	.024	0.40	0.60	
L	.083	.098	2.10	2.50	
М	.018	.026	0.45	0.65	
N	.031	.051	0.80	1.30	

# SBL10B45DH

T0-252





DIMENSIONS						
DIM	INCHES		MILLIMETERS		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	.380	.400	9.65	10.15		
В	.250	.266	6.35	6.75		
С	.201	.217	5.10	5.50		
D	.033	.053	0.85	1.35		
Ε	.228	.248	5.80	6.30		
F	.049	.065	1.25	1.65		
Н	.085	.096	2.15	2.45		
1	.030	.041	0.75	1.05		
J	.016	.024	0.40	0.60		
L	.083	.098	2.10	2.50		
М	.018	.026	0.45	0.65		
N	.031	.051	0.80	1.30		



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